IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No
Filing Date December 4, 2000
Inventor
Assignee Micron Technology, Inc.
Group Art Unit
Examiner
Attorney's Docket No
Title: Field Effect Transistors, Integrated Circuitry, Methods of Forming Field
Effect Transistor Gates, and Methods of Forming Integrated Circuitry

AMENDED PRELIMINARY AMENDMENT

To:

Box Non-Fee Amendment

Assistant Commissioner for Patents

Washington, D.C. 20231

From:

Mark S. Matkin (Tel. 509-624-4276; Fax 509-838-3424)

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Please enter the following amendments prior to examining the aboveidentified application.

AMENDMENTS

In the Specification

At p. 1 before the "Technical Field" section, please insert the following: